

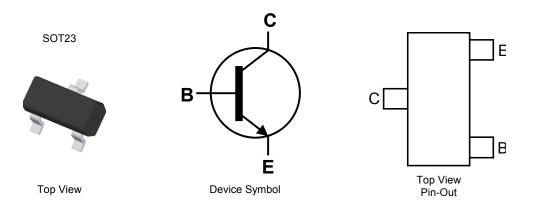
40V NPN SMALL SIGNAL TRANSISTOR IN SOT23

Features

- Epitaxial Planar Die Construction
- Complementary PNP Type: MMBT2907A
- Ideal for Low Power Amplification and Switching
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP capable (Note 4)

Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Leads; Solderable per MIL-STD-202, Method 208 63
- Weight: 0.008 grams (approximate)



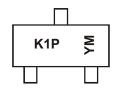
Ordering Information (Notes 4 & 5)

Product	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
MMBT2222A-7-F	AEC-Q101	K1P	7	8	3,000
MMBT2222A-13-F	AEC-Q101	K1P	13	8	10,000
MMBT2222AQ-7-F	Automotive	K1P	7	8	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product_compliance_definitions/.
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



K1P = Product Type Marking Code YM = Date Code Marking Y or \overline{Y} = Year (ex: A = 2013) M or \overline{M} = Month (ex: 9 = September)

Date Code Key

Year	2010		2011	2012		2013	2014		2015	2016		2017
Code	Х		Υ	Z		Α	В		С	D		E
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	75	V
Collector-Emitter Voltage	V _{CEO}	40	V
Emitter-Base Voltage	V _{EBO}	6.0	V
Collector Current	Ic	600	mA
Peak Collector Current	Ісм	800	mA
Peak Base Current	I _{BM}	200	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Collector Power Dissipation	(Note 6)	0	310	mW	
Collector Fower Dissipation	(Note 7)	P_{D}	350		
Thermal Resistance, Junction to Ambient	(Note 6)	D	403	°C/W	
Thermal Resistance, Junction to Ambient	(Note 7)	$R_{ heta JA}$	357	C/VV	
Thermal Resistance, Junction to Leads (Note 8)		$R_{ heta JL}$	350	°C/W	
Operating and Storage Temperature Range	T_{J} , T_{STG}	-55 to +150	°C		

ESD Ratings (Note 9)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

- 6. For a device mounted on minimum recommended pad layout 1oz copper that is on a single-sided FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

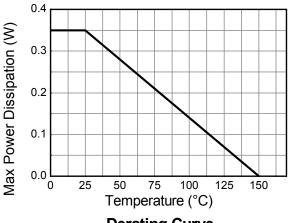
 7. Same as note (6), except the device is mounted on 15 mm x 15mm 1oz copper.

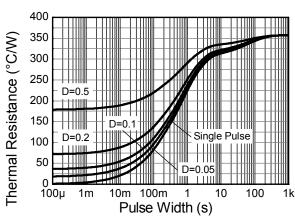
 8. Thermal resistance from junction to solder-point (at the end of the leads).

 9. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



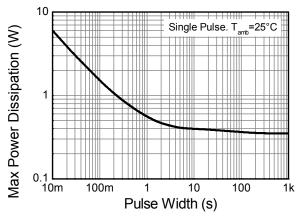
Thermal Characteristics and Derating Information





Derating Curve

Transient Thermal Impedance



Pulse Power Dissipation



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Max	Unit	Test Condition	
OFF CHARACTERISTICS						
Collector-Base Breakdown Voltage	BV _{CBO}	75	_	V	$I_C = 100\mu A, I_E = 0$	
Collector-Emitter Breakdown Voltage (Note 10)	BV_{CEO}	40	_	V	I _C = 10mA, I _B = 0	
Emitter-Base Breakdown Voltage	BV _{EBO}	6.0	_	V	$I_E = 100\mu A, I_C = 0$	
Collector Cutoff Current	I _{CBO}	_	10	nΑ μΑ	V _{CB} = 60V, I _E = 0 V _{CB} = 60V, I _E = 0, T _A = +150°C	
Collector Cutoff Current	I _{CEX}	_	10	nA	V _{CE} = 60V, V _{EB(OFF)} = 3.0V	
Collector Cutoff Current	I _{CEV}		10	nA	$V_{CE} = 60V, V_{BE} = \pm 0.25V$	
Emitter Cutoff Current	I _{EBO}		10	nA	V _{EB} = 5.0V, I _C = 0	
Base Cutoff Current	I _{BL}		20	nA	V _{CE} = 60V, V _{EB(OFF)} = 3.0V	
ON CHARACTERISTICS (Note 10)						
DC Current Gain	h _{FE}	35 50 75 100 40 50 35		_	$\begin{split} &I_{C} = 100 \mu A, \ V_{CE} = 10 V \\ &I_{C} = 1.0 m A, \ V_{CE} = 10 V \\ &I_{C} = 10 m A, \ V_{CE} = 10 V \\ &I_{C} = 150 m A, \ V_{CE} = 10 V \\ &I_{C} = 500 m A, \ V_{CE} = 10 V \\ &I_{C} = 10 m A, \ V_{CE} = 10 V, \ T_{A} = -55 ^{\circ} C \\ &I_{C} = 150 m A, \ V_{CE} = 1.0 V \end{split}$	
Collector-Emitter Saturation Voltage	V _{CE(sat)}	_	0.3 1.0	V	I _C = 150mA, I _B = 15mA I _C = 500mA, I _B = 50mA	
Base-Emitter Saturation Voltage	V _{BE(sat)}	0.6	1.2 2.0	V	I _C = 150mA, I _B = 15mA I _C = 500mA, I _B = 50mA	
SMALL SIGNAL CHARACTERISTICS			l.	l .		
Output Capacitance	C _{obo}	_	8	pF	V _{CB} = 10V, f = 1.0MHz, I _E = 0	
Input Capacitance	C _{ibo}	_	25	pF	V _{EB} = 0.5V, f = 1.0MHz, I _C = 0	
Current Gain-Bandwidth Product	f _T	300	_	MHz	V _{CE} = 20V, I _C = 20mA, f = 100MHz	
Noise Figure	NF	_	4.0	dB	V_{CE} = 10V, I_{C} = 100 μ A, R _S = 1.0k Ω , f = 1.0kHz	
SWITCHING CHARACTERISTICS						
Delay Time	t _d	_	10	ns	V_{CC} = 30V, I_C = 150mA, $V_{BE(OFF)}$ = - 0.5V, I_{B1} = 15mA	
Rise Time	t _r	_	25	ns	V_{CC} = 3.0V, I_{C} = 150mA, I_{B1} = 15mA, $V_{BE(OFF)}$ = 0.5V	
Storage Time	ts	_	225	ns	$V_{CC} = 30V, I_C = 150mA,$ $I_{B1} = I_{B2} = 15mA$	
Fall Time	t _f	_	60	ns	V _{CC} = 30V, I _C = 150mA, I _{B1} = I _{B2} = 15mA	

Note: 10. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.



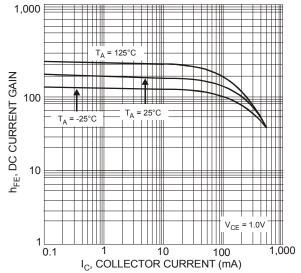
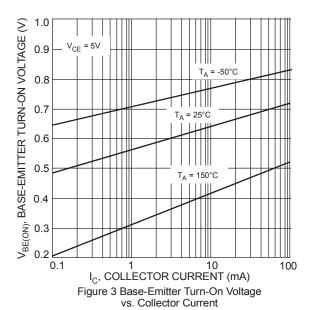
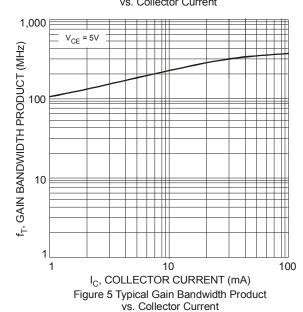


Figure 1 Typical DC Current Gain vs. Collector Current





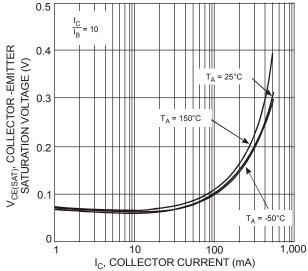


Figure 2 Typical Collector-Emitter Saturation Voltage vs. Collector Current

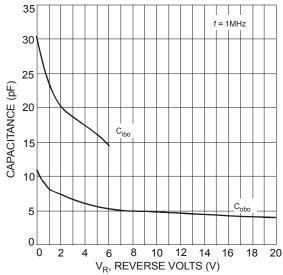


Figure 4 Typical Capacitance Characteristics

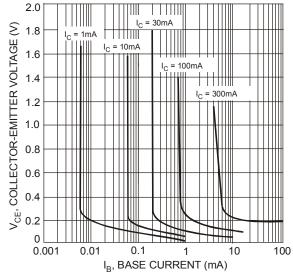
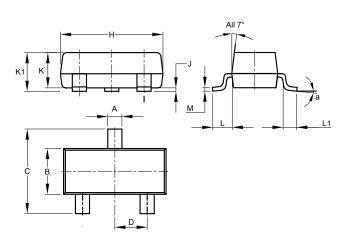


Figure 6 Typical Collector Saturation Region



Package Outline Dimensions

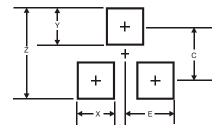
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



	SOT23						
Dim	Min	Max	Тур				
Α	0.37	0.51	0.40				
В	1.20	1.40	1.30				
С	2.30	2.50	2.40				
D	0.89	1.03	0.915				
F	0.45	0.60	0.535				
G	1.78	2.05	1.83				
Н	2.80	3.00	2.90				
J	0.013	0.10	0.05				
K	0.890	1.00	0.975				
K1	0.903	1.10	1.025				
L	0.45	0.61	0.55				
L1	0.25	0.55	0.40				
M	0.085	0.150	0.110				
а	8°						
All	All Dimensions in mm						

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.9
Х	8.0
Υ	0.9
С	2.0
E	1.35



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